

rfmd.com

DC to 5000 MHz, CASCADABLE SiGe HBT MMIC AMPLIFIER

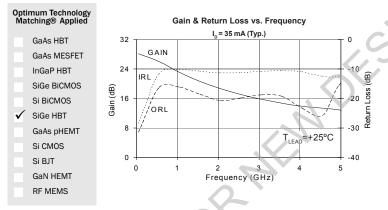
Package: SOT-86



Ø 🏺

Product Description

The SGA3586Z is a high performance SiGe HBT MMIC Amplifier. A Darlington configuration featuring one-micron emitters provides high $F_{\rm T}$ and excellent thermal performance. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. Cancellation of emitter junction non-linearities results in higher suppression of intermodulation products. Only two DC-blocking capacitors, a bias resistor, and an optional RF choke are required for operation.



Features

- High Gain: 25 dB at 850 MHz
- Cascadable 50Ω Gain Block
- High Output IP₃: 25dBm typ. at 1950MHz
- Low Noise Figure: 2.5 dB typ. at 1950 MHz
- Low Current Draw: 35 mA typ.
- Single Voltage Supply Operation

Applications

- PA Driver Amplifier
- Cellular, PCS, GSM, UMTS
- IF Amplifier
- Wireless Data, Satellite

Parameter	Specification			Unit	Condition		
r di di licito	Min.	Тур.	Max.	Onic	Condition		
Small Signal Gain	22.5	25.0	27.5	dB	850MHz		
	18.0	20.0	22.0	dB	1950MHz		
		18.5		dB	2400 MHz		
Output Power at 1dB Compression		13.0		dBm	850 MHz		
	11.0	12.5		dBm	1950MHz		
Output Third Intercept Point		24.5		dBm	850 MHz		
	23.0	25.0		dBm	1950MHz		
Bandwidth Determined by Return Loss		5000		MHz	>10dB		
Input Return Loss	9.5	11.0		dB	1950MHz		
Output Return Loss	14.0	20.0		dB	1950MHz		
Noise Figure		2.5	3.5	dB	1950MHz		
Device Operating Voltage	3.0	3.25	3.5	V			
Device Operating Current	31	35	39	mA			
Thermal Resistance (Junction - Lead)		97		°C/W			

Test Conditions: I_D =35mA Typ., T_{LEAD} =25°C, Z_S = Z_L =50 Ω , P_{OUT} per tone=-5dBm, OIP₃ Tone Spacing=1MHz

RF MICRO DEVICES®, RFMDB, Optimum Technology Matching®, Enabling Wireless Connectivity¹⁰, PowerStart(N, RANDO¹⁰ and UltimateBlue¹⁰ are trademarks of RFMD, LLC, BLUETOOTH is a trade mark/owned N Eulardon SIX, or LLI SA, and Independent on RFMD, all other trade names related are trademarks and relatives to the nomether of their researcher averse. (#2000c. EM Micro Burley)



rfmd.com

Absolute Maximum Ratings

Parameter	Rating	Unit
Max Device Current (I _D)	70	mA
Max Device Voltage (V _D)	6	V
Max RF Input Power	+18	dBm
Max Junction Temp (T _J)	+150	°C
Operating Temp Range (T_L)	-55 to +110	°C
Max Storage Temp	+150	°C

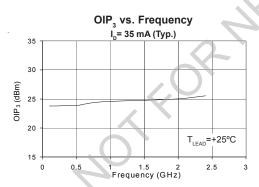
Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one. Bias Conditions should also satisfy the following expression:

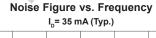
 $I_{\rm D}V_{\rm D} < (T_{\rm J} - T_{\rm L})/R_{\rm TH}, j-1$

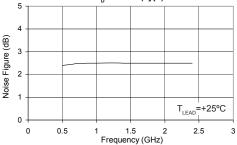
Typical Performance at Key Operating Frequencies

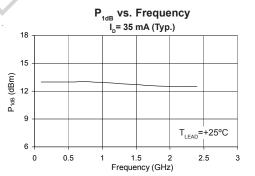
Parameter	Unit	100	500	850	1950	2400	3500
		MHz	MHz	MHz	MHz	MHz	MHz
Small Signal Gain	dB	28.2	27.1	25.0	19.7	18.3	14.8
Output Third Order Intercept Point	dBm	23.8	23.9	24.5	25.0	25.5	
Output Power at 1dB Compression	dBm	13.0	13.0	13.0	12.5	12.5	
Input Return Loss	dB	28.4	12.8	10.7	10.5	11.1	10.6
Output Return Loss	dB	31.5	17.1	15.9	20.5	20.3	18.9
Reverse Isolation	dB	29.4	29.0	28.1	24.1	22.4	19.2
Noise Figure	dB		2.4	2.5	2.5	2.5	

Test Conditions: $I_D = 35 \text{ mA Typ.}$, OIP₃ Tone Spacing=1MHz, P_{OUT} per tone=-5dBm, $R_{BIAS} = 100\Omega$, $T_L = 25^{\circ}C$, $Z_S = Z_L = 50\Omega$









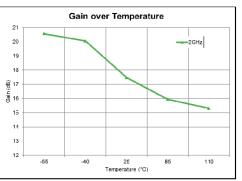
Caution! ESD sensitive device.

solder.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical perfor-mance or functional operation of the device under Absolute Maximum Rating condi-tions is not implied. The information is believed to be accurate and reliable. However, no

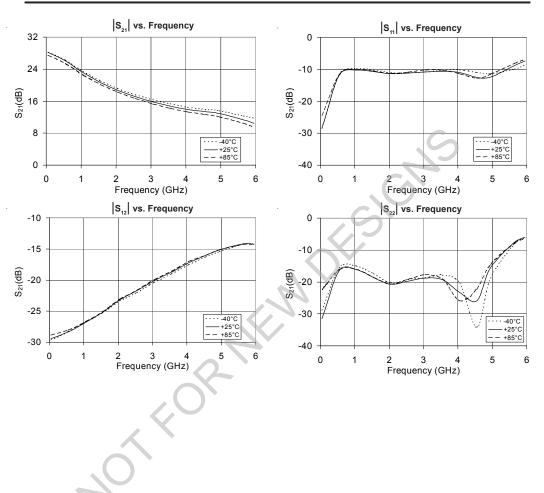
The morimation in this publication is believed to be according and reliable, notweek, in responsibility is assumed by R Micro Devices, inc. (RFRM) for its use, norifor any infringement of patentis, or other rights of third particles, resulting from its use. No license is granued by implication or otherwise under any patent or patent rights of RFMD. RFMD reserves the right to change component circuitry, recommended appli-cation circuitry and specifications at any time without prior notice.

65/EURFMD Green: RoHS compliant per EU Directive 2011/65/EU, halogen free per IEC 61249-2-21, < 1000 ppm each of antimony trioxide in polymeric materials and red phosphorus as a flame retardant, and <2% antimony in



7628 Thorndike Road, Greensboro, NC 27409-9421 · For sales or technical support, contact RFMD at (+1) 336-678-5570 or sales-support@rfmd.com.





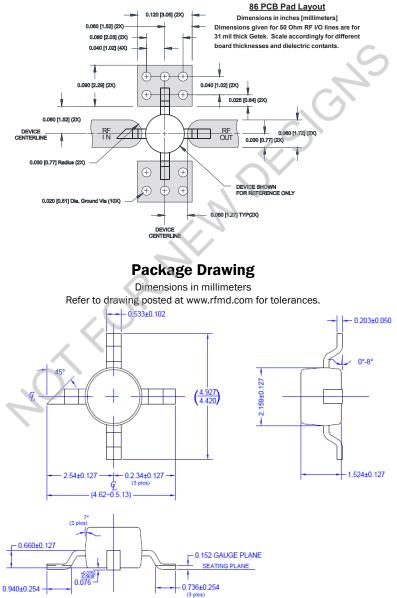
Typical RF Performance Over Lead Temperature -- Bias: I_D= 35 mA (Typ.) at T_{LEAD} = +25°C

RFMD 💷

rfmd.com

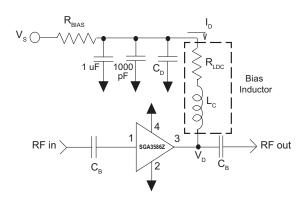
Pin	Function	Description
1	RF IN	RF input pin. This pin requires the use of an external DC-blocking capacitor chosen for the frequency of operation.
2, 4	GND	Connection to ground. For optimum RF performance, use via holes as close to ground leads as possible to reduce lead inductance.
3	RF OUT/BIAS	RF output and bias pin. DC voltage is present on this pin, therefor a DC-blocking capacitor is necessary for proper opera- tion.

Suggested Pad Layout





Application Schematic



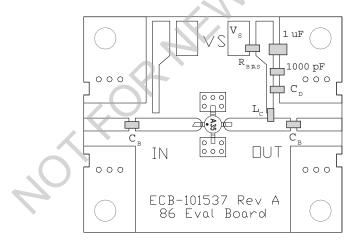
Application Circuit Element Values									
Reference	Frequency (Mhz)								
Designator	100	500	850	1950	2400	3500			
C _B	1000 pF	220 pF	100 pF	68 pF	56 pF	39 pF			
CD	100 pF	100 pF	68 pF	22 pF	22 pF	15 pF			
L _c	470 nH	68 nH	33 nH	22 nH	18 nH	15 nH			

Recommended Bias Resistance for $I_0 = 35$ mA							
Supply Voltage (V _S) (Volts)	< 5	5	6	7	8	9	10
Bias Resistance* (Ohms)	N/R	50	79	107	136	164	193
* Bias Resistance = R _{BIAS} + R _{LDC} = (V _s -V _D) / I _D							

Select \mathbf{R}_{BMS} so that $\mathbf{R}_{\text{BMS}} + \mathbf{R}_{\text{LDC}} \sim$ the recommended bias resistance. Use 1% or 5% tolerance resisisfors or parallel combinations to attain the recommended bias resistance +/- 3%. \mathbf{R}_{BMS} provides current stability over temperature.

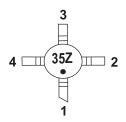
* N/R=Not Recommended. Contact Sirenza technical support for guidance when available supply voltage is less than 5 Volts.

Evaluation Board Layout





Part Identification



Ordering Information

Ordering Code	Description	
SGA3586Z	13" Reel with 3000 pieces	
SGA3586ZSQ	Sample bag with 25 pieces	
SGA3586ZSR	7" Reel with 100 pieces	
SGA3586ZPCK1	850MHz, 5V Operation PCBA with 5-piece sample bag	

NOT FOR MENDE

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Qorvo: SGA3586Z